



N 沟道增强型场效应晶体管

N-CHANNEL MOSFET

FHP1906A

主要参数 MAIN CHARACTERISTICS

ID	100A
VDSS	60V
Rdson-typ (@Vgs=10V)	5mΩ
Qg-typ	82nC

用途 APPLICATIONS

高频开关电源	High efficiency switch mode power supplies
逆变电源	Power management for inverter systems

产品特性 FEATURES

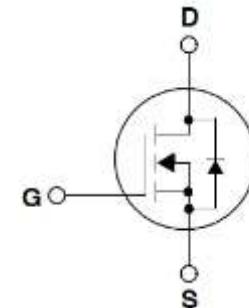
低栅极电荷	Low gate charge
低 Crss (典型值 275pF)	Low Crss (typical 275pF)
开关速度快	Fast switching
100% 经过雪崩测试	100% avalanche tested
高抗 dv/dt 能力	Improved dv/dt capability
RoHS 产品	RoHS product

封装形式 Package



TO-220
FHP 系列

等效电路 Equivalent Circuit



绝对最大额定值 ABSOLUTE RATINGS (Tc=25°C)

项目 Parameter	符号 Symbol	数值 Value	单位 Unit
		FHP1906A	
最高漏极—源极直流电压 Drain-Source Voltage	VDS	60	V
连续漏极电流* Drain Current -continuous *	ID (Tc=25°C)	100	A
	ID (Tc=100°C)	65	A
最大脉冲漏极电流 (注 1) Drain Current – pulse (note 1)	IDM	400	A
最高栅源电压 Gate-Source Voltage	VGS	±30	V
单脉冲雪崩能量 (注 2) Single Pulsed Avalanche Energy (note 2)	EAS	220	mJ
雪崩电流 (注 1) Avalanche Current (note 1)	IAR	21	A
重复雪崩能量 (注 1) Repetitive Avalanche Current (note 1)	EAR	13	mJ
二极管反向恢复最大电压变化速率 (注 3) Peak Diode Recovery dv/dt (note 3)	dv/dt	5.0	V/ns
耗散功率 Power Dissipation	PD (TC=25°C)	130	W
	-Derate above 25°C	1.04	W/°C
最高结温及存储温度 Operating and Storage Temperature Range	TJ, TSTG	150, -55 to 150	°C
引线最高焊接温度 Maximum Lead Temperature for Soldering Purposes	TL	300	°C

*漏极电流由最高结温限制

*Drain current limited by maximum junction temperature

电特性 ELECTRICAL CHARACTERISTICS

项目 Parameter	符号 Symbol	测试条件 Tests conditions	最小 Min	典型 Typ	最大 Max	单位 Units	
关态特性 Off -Characteristics							
漏一源击穿电压 Drain-Source Voltage	BV_{DSS}	$I_D=250\mu A, V_{GS}=0V$	60	-	-	V	
击穿电压温度特性 Breakdown Voltage Temperature Coefficient	$\Delta BV_{DSS}/\Delta T_J$	$I_D=250\mu A$, referenced to 25°C	-	0.11	-	V/°C	
零栅压下漏极漏电流 Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=60V, V_{GS}=0V, T_c=25^{\circ}C$	-	-	1	μA	
		$V_{DS}=48V, T_c=125^{\circ}C$	-	-	100	μA	
栅极体漏电流 Gate-body leakage current	$I_{GSS} (F/R)$	$V_{DS}=0V, V_{GS}=\pm 30V$	-	-	± 100	μA	
通态特性 On-Characteristics							
阈值电压 Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D=250\mu A$	2.0	-	4.0	V	
静态导通电阻 Static Drain-Source On-Resistance	$R_{DS(ON)}$	$V_{GS} = 10V, I_D=50A$	-	5	7	$m\Omega$	
正向跨导 Forward Transconductance	g_{fs}	$V_{DS} = 40V, I_D=50A$ (note 4)	-	80	-	S	
动态特性 Dynamic Characteristics							
输入电容 Input capacitance	C_{iss}	$V_{DS}=20V,$ $V_{GS}=0V,$ $f=1.0MHz$	-	3485	-	pF	
输出电容 Output capacitance	C_{oss}		-	370	-		
反向传输电容 Reverse transfer capacitance	C_{rss}		-	275	-		
开关特性 Switching Characteristics							
延迟时间 Turn-On delay time	$t_{d(on)}$	$V_{DS}=30V,$ $I_D=5A,$ $R_G=6.8\Omega$ $V_{GS}=10V$ (note 4, 5)	-	26	-	ns	
上升时间 Turn-On rise time	t_r		-	125	-	ns	
延迟时间 Turn-Off delay time	$t_{d(off)}$		-	58	-	ns	
下降时间 Turn-Off Fall time	t_f		-	112	-	ns	
栅极电荷总量 Total Gate Charge	Q_g	$V_{DS}=24V,$ $I_D=10A,$ $V_{GS}=10V$ (note 4, 5)	-	82	-	nC	
栅一源电荷 Gate-Source charge	Q_{gs}		-	13	-	nC	
栅一漏电荷 Gate-Drain charge	Q_{gd}		-	17	-	nC	
漏一源二极管特性及最大额定值 Drain-Source Diode Characteristics and Maximum Ratings							
正向最大连续电流 Maximum Continuous Drain -Source Diode Forward Current	I_S		-	-	100	A	
正向最大脉冲电流 Maximum Pulsed Drain-Source Diode Forward Current	I_{SM}		-	-	400	A	
正向压降 Drain-Source Diode Forward Voltage	V_{SD}	$V_{GS}=0V, I_S=40A$	-	-	1.4	V	
反向恢复时间 Reverse recovery time	t_{rr}	$V_{GS}=0V, I_S=10A, dI/dt=100A/\mu s$ (note 4)	-	38	-	ns	
反向恢复电荷 Reverse recovery charge	Q_{rr}		-	44	-	nC	

热特性 THERMAL CHARACTERISTIC

项目 Parameter	符号 Symbol	FHP1906A	单位 Unit
结到管壳的热阻 Thermal Resistance, Junction to Case	R _{th(j-c)}	1.5	°C/W
结到环境的热阻 Thermal Resistance, Junction to Ambient	R _{th(j-A)}	62.5	°C/W

注释:

- 1: 脉冲宽度由最高结温限制
- 2: L=1mH, IAS=21A, VDD=48V, RG=25 Ω, 起始结温 TJ=25°C
- 3: ISD ≤100A,di/dt ≤300A/μs,VDD≤BV_{DSS},起始结温 TJ=25°C
- 4: 脉冲测试: 脉冲宽度 ≤300μs,占空比≤2%
- 5: 基本与工作温度无关

Notes:

- 1: Pulse width limited by maximum junction temperature
- 2: L=1mH, ID=21A, VDD=48V, RG=25 Ω ,Start TJ=25°C;
- 3: ISD ≤100A,di/dt ≤100A/μs,VDD≤BV_{DSS}, Starting TJ=25°C
- 4: Pulse Test: Pulse Width ≤300μs,Duty Cycle≤2%
- 5: Essentially independent of operating temperature

特性曲线 (ELECTRICAL CHARACTERISTICS (curves))

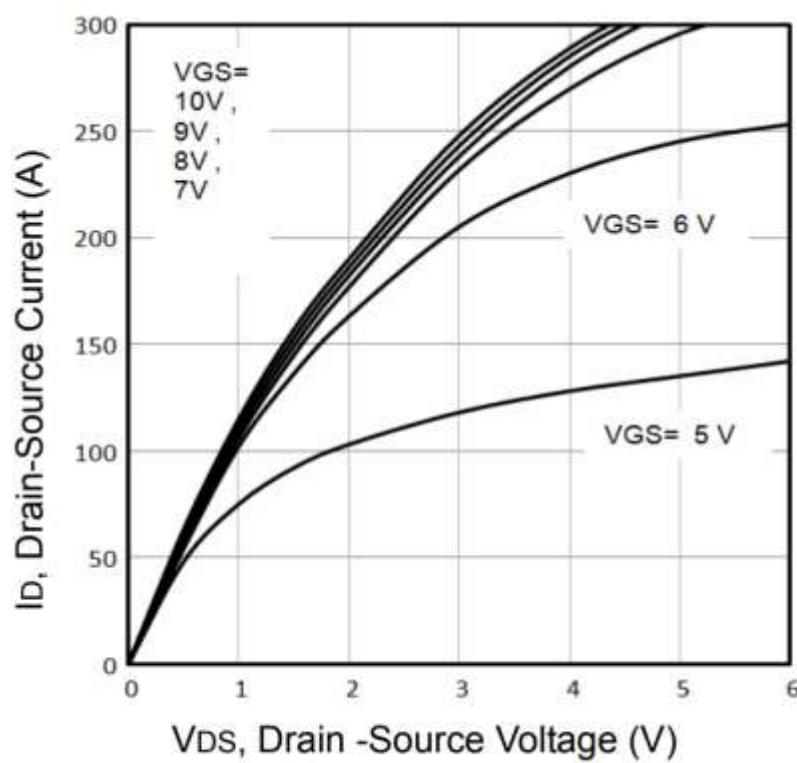


Fig1. Typical Output Characteristics

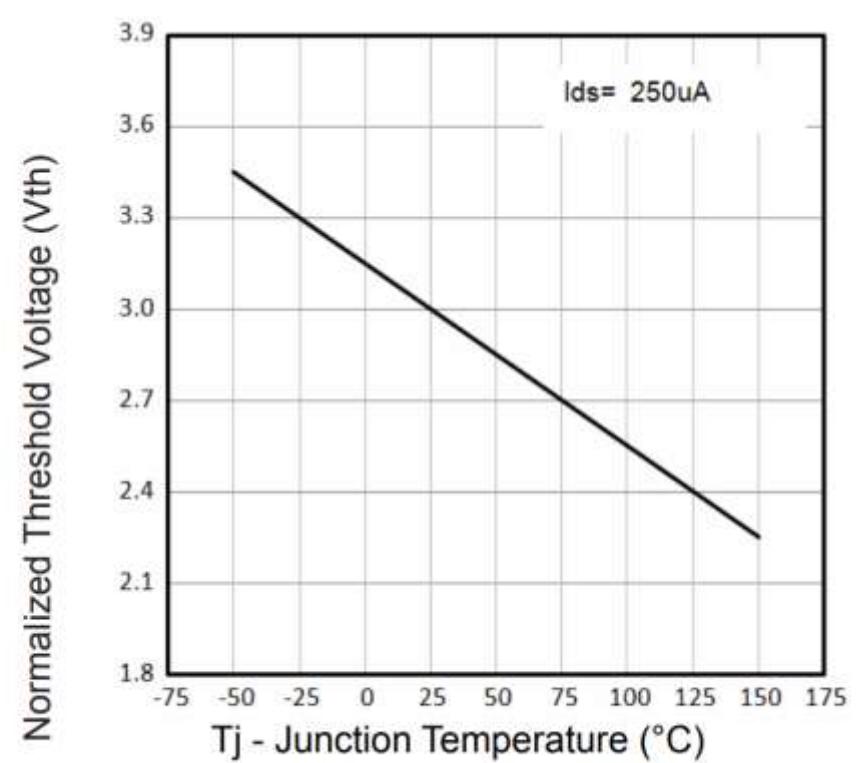


Fig2. Normalized Threshold Voltage Vs. Temperature

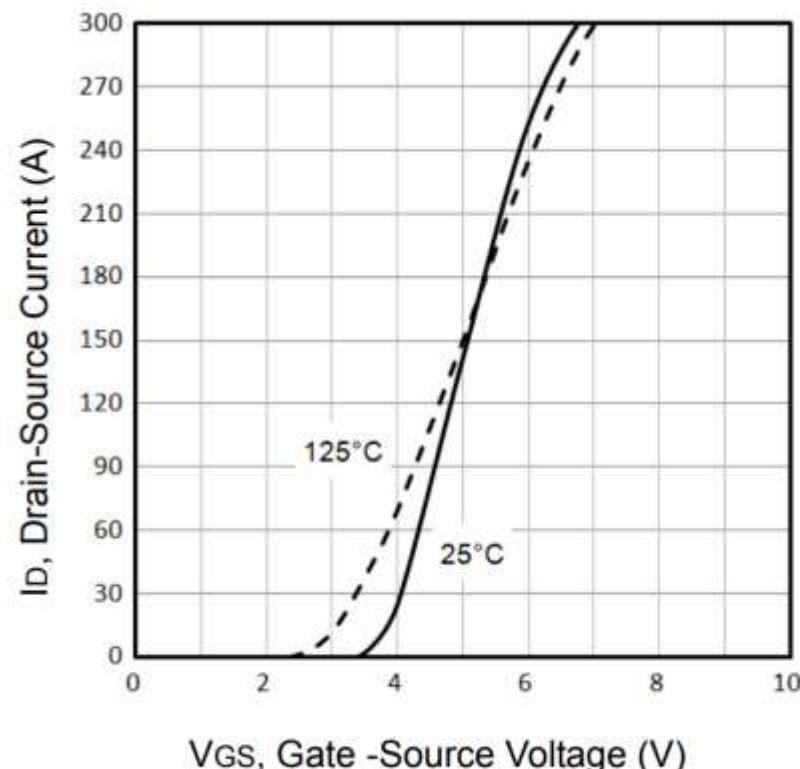


Fig3. Typical Transfer Characteristics

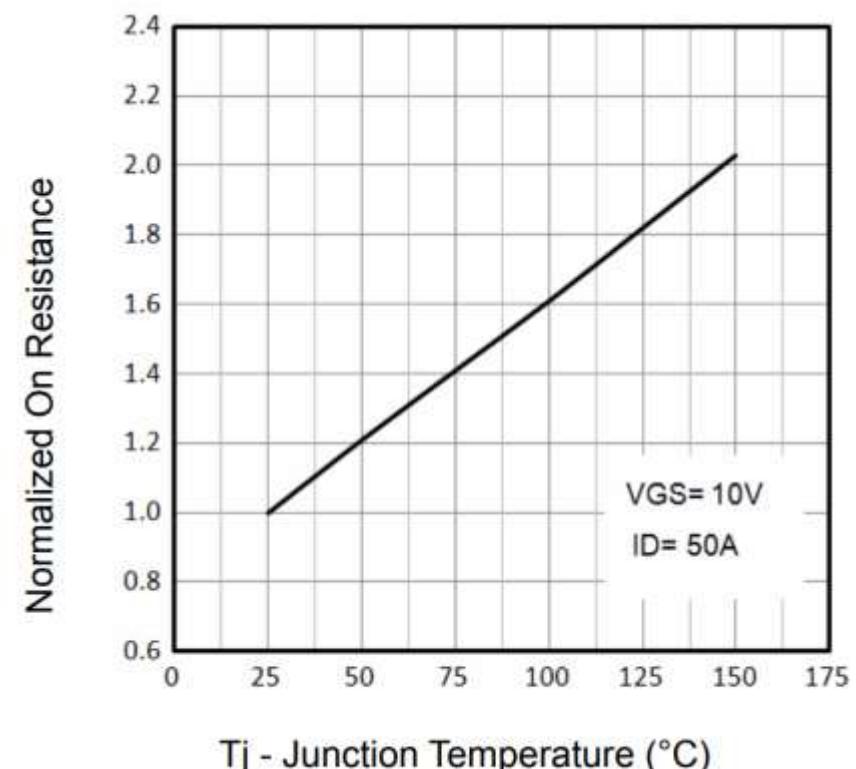


Fig4. Normalized On-Resistance Vs. Temperature

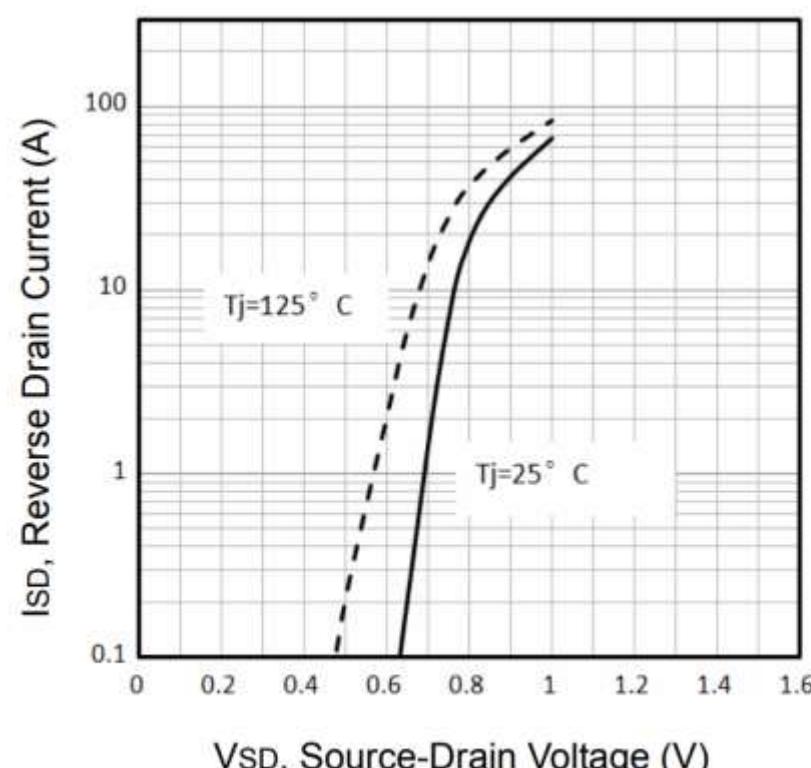


Fig5. Typical Source-Drain Diode Forward Voltage

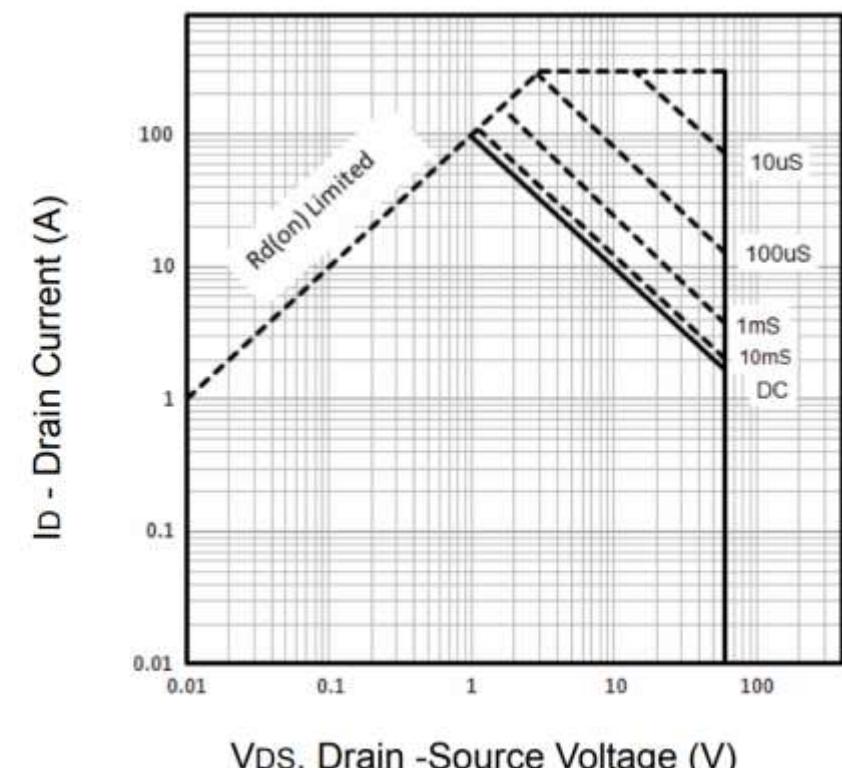


Fig6. Maximum Safe Operating Area

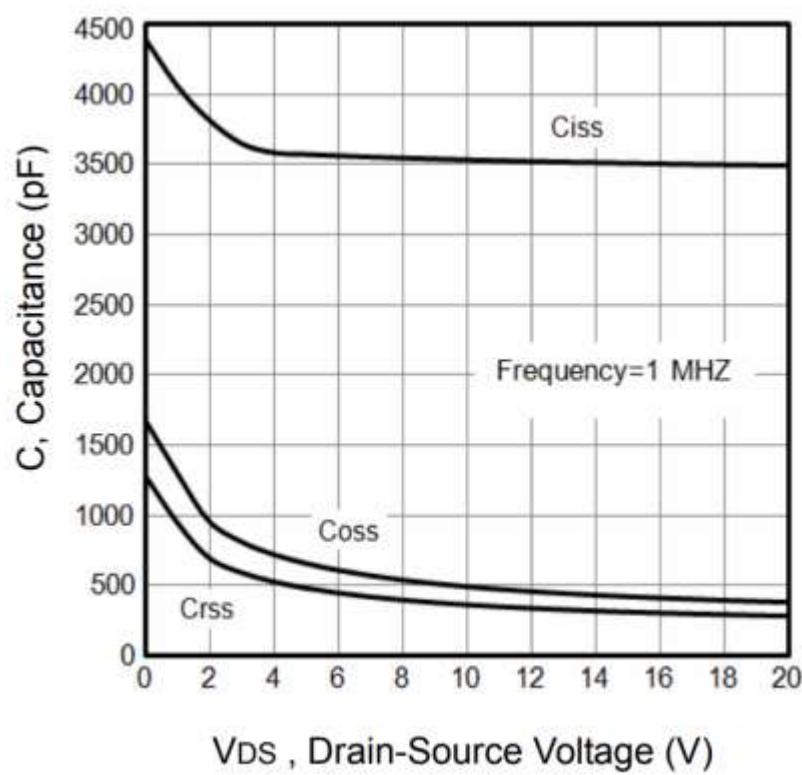


Fig7. Typical Capacitance Vs.Drain-Source Voltage

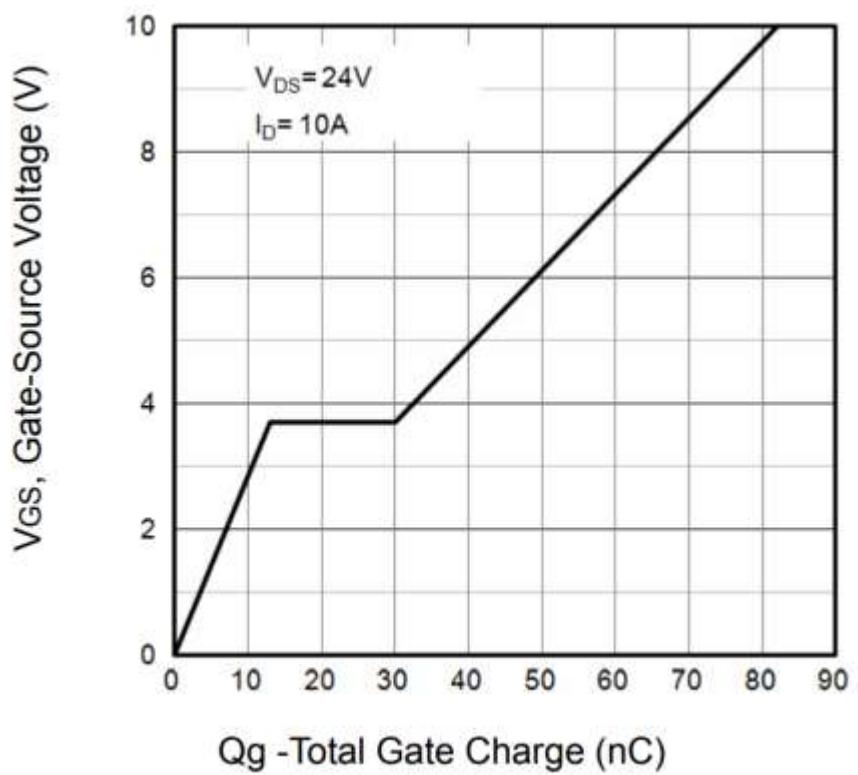


Fig8. Typical Gate Charge Vs.Gate-Source Voltage

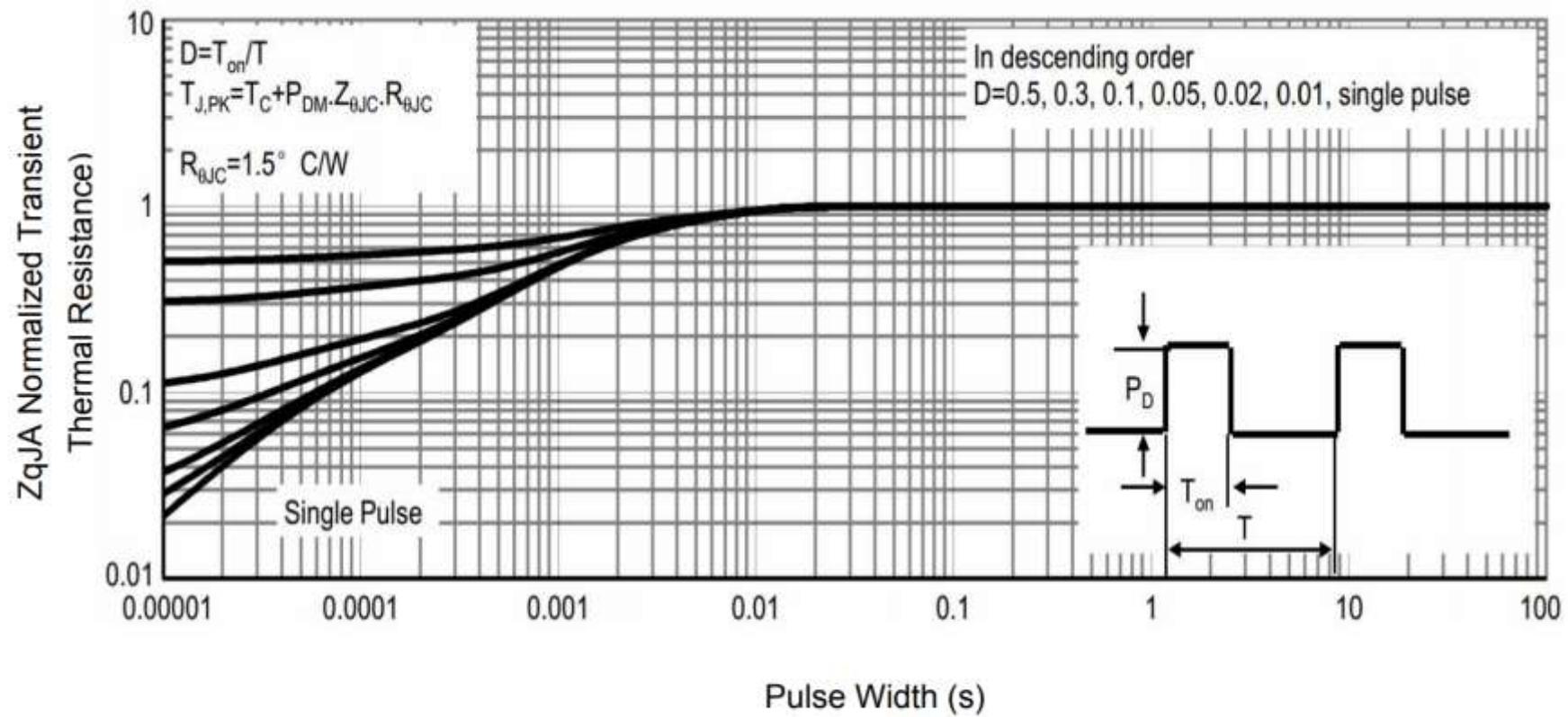
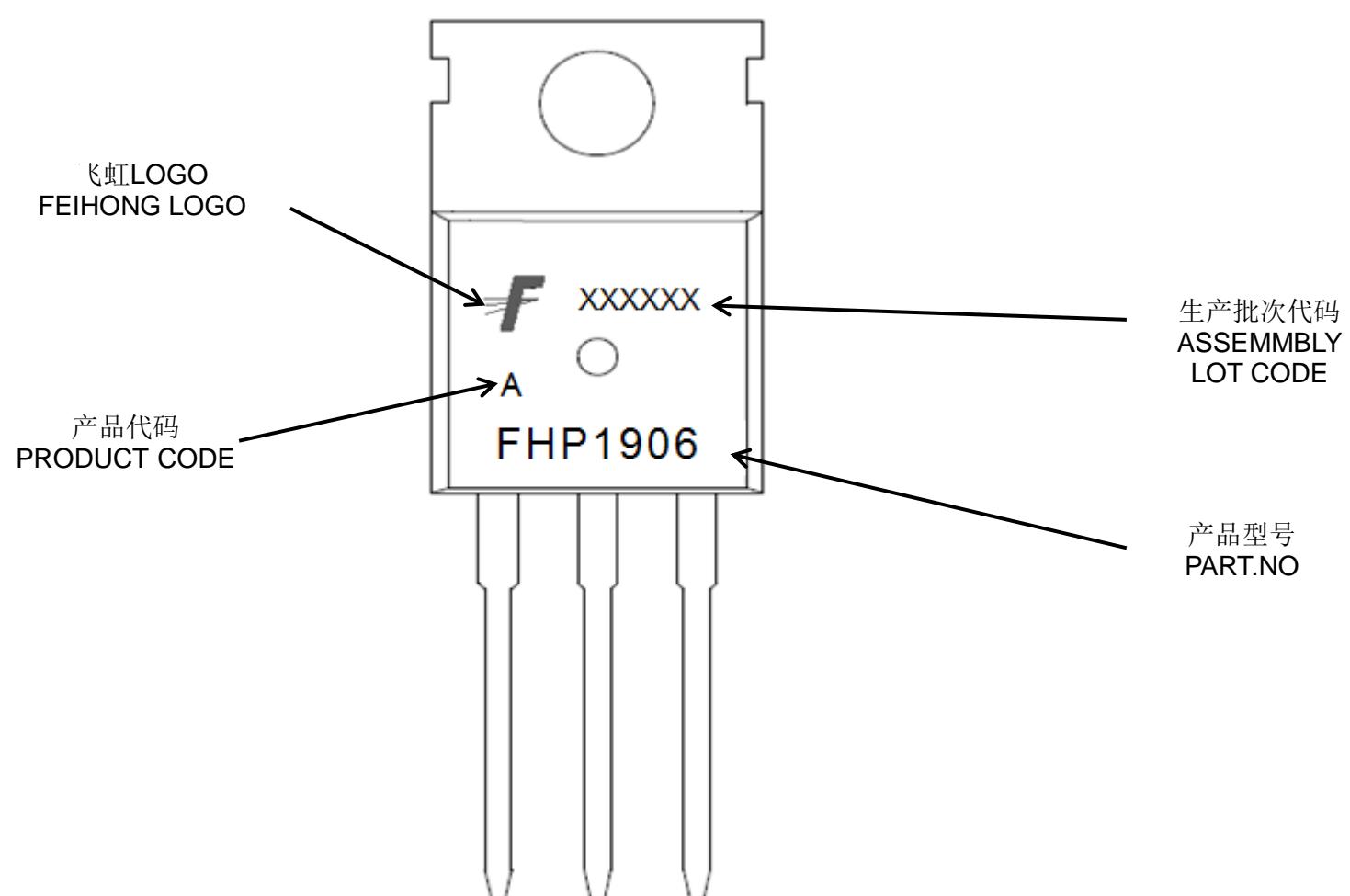


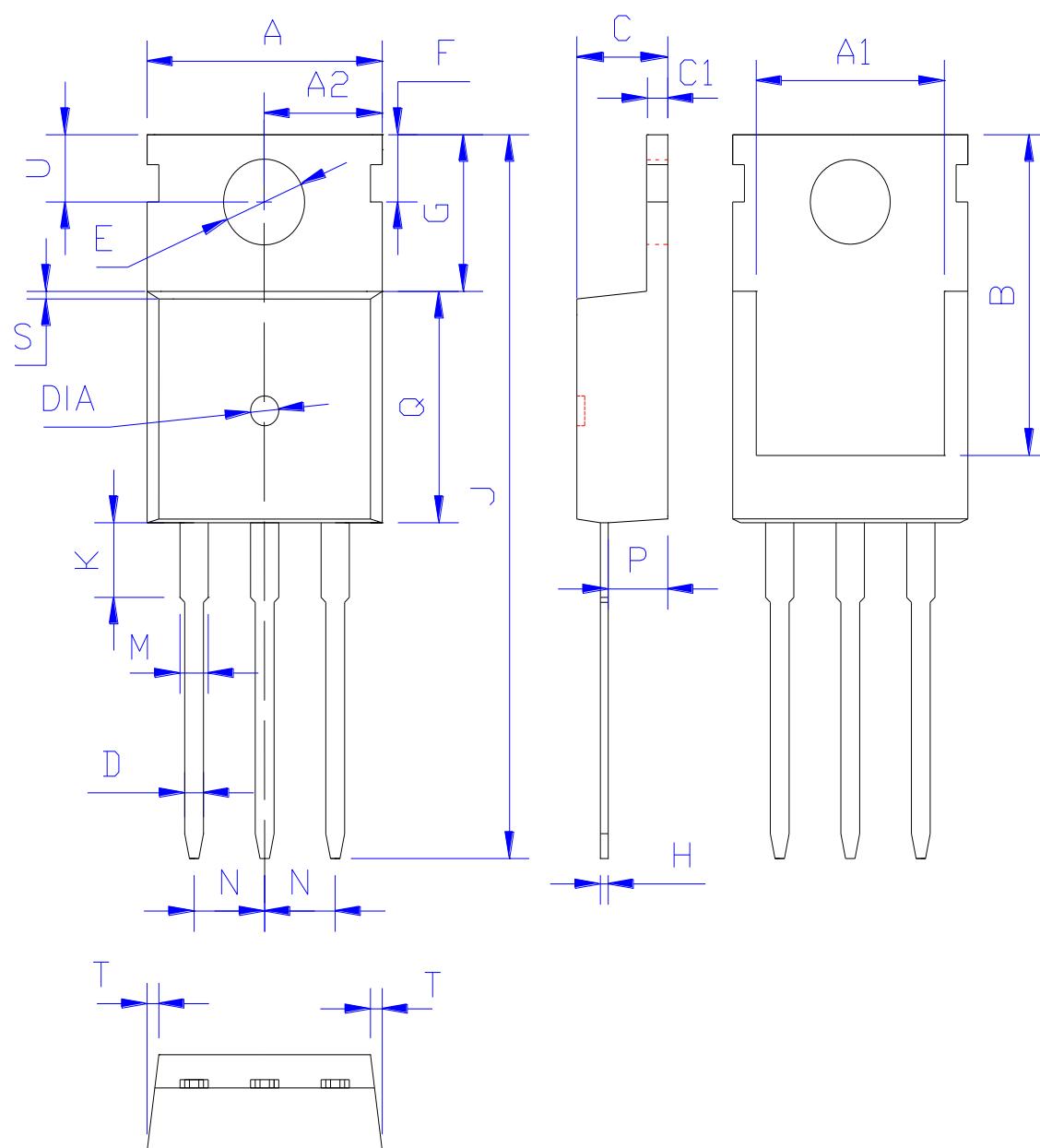
Fig9. Normalized Maximum Transient Thermal Impedance

印记 Marking:



外形尺寸:
Package Dimension:

TO-220



DIM	MILLIMETERS
A	10.00 ± 0.30
A1	8.00 ± 0.30
A2	5.00 ± 0.30
B	13.20 ± 0.40
C	4.50 ± 0.20
C1	1.30 ± 0.20
D	0.80 ± 0.20
E	3.60 ± 0.20
F	3.00 ± 0.30
G	6.60 ± 0.40
H	0.50 ± 0.20
J	28.88 ± 0.50
K	3.00 ± 0.30
M	1.30 ± 0.30
N	Typical 2.54
P	2.40 ± 0.40
Q	9.20 ± 0.40
S	0.25 ± 0.15
T	0.25 ± 0.15
U	2.80 ± 0.30
DIA	宽 1.50 ± 0.10 深 0.50 MAX

(Units: mm)

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